

1. Electron mobility of the following intrinsic elements in descending order is:

- (a) GaAs, Ge, Si  
 (b) GaAs, Si, Ge  
 (c) Si, Ge, GaAs  
 (d) Ge, Si, GaAs

2. A sample of Si is doped with  $10^{17}$  donor atoms/cm<sup>3</sup>. Considering electron mobility in the doped Si  $700 \text{ cm}^2/\text{V-sec}$ , the approximate resistivity of the doped Si is:

- (a)  $1 \Omega\text{-cm}$   
 (b)  $10 \Omega\text{-cm}$   
 (c)  $0.1 \Omega\text{-cm}$   
 (d)  $100 \Omega\text{-cm}$

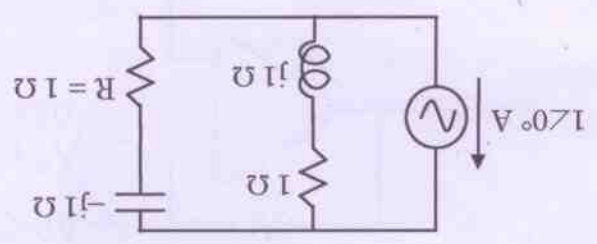
3. Common-base current gain of a p-n-p bipolar transistor is 0.99. The common emitter current gain of the transistor is:

- (a) 101  
 (b) 0.01  
 (c) 99  
 (d) 1.0

4. The electrical conductivity of a semiconductor increases when a radiation of wavelength shorter than  $1000 \text{ nm}$  is incident on it. The band gap of the semiconductor is:

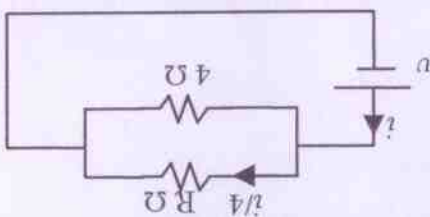
- (a)  $2.4 \text{ eV}$   
 (b)  $1.2 \text{ eV}$   
 (c)  $3.4 \text{ eV}$   
 (d)  $4.0 \text{ eV}$

5. The voltage across the resistor R is:



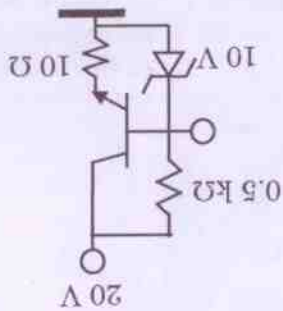
- (a)  $1/\sqrt{3} \angle 0^\circ \text{ V}$   
 (b)  $1/\sqrt{2} \angle 0^\circ \text{ V}$   
 (c)  $1/2 \angle 45^\circ \text{ V}$   
 (d)  $1/\sqrt{2} \angle 45^\circ \text{ V}$

6. The effective resistance faced by the voltage source is:



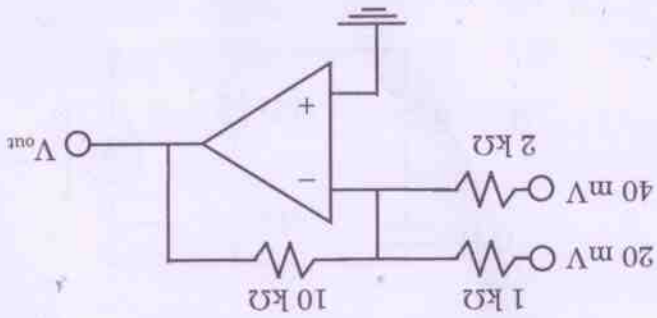
- (a)  $4\ \Omega$  (b)  $12\ \Omega$  (c)  $3\ \Omega$  (d)  $16\ \Omega$

7. Common emitter DC current gain of the transistor is 100. The current through the  $10\ \text{V}$  Zener diode (assuming  $V_{BE}$  of the transistor is  $0.7\ \text{V}$ ) is:



- (a)  $10.3\ \text{mA}$  (b)  $19.3\ \text{mA}$  (c)  $20\ \text{mA}$  (d)  $40\ \text{mA}$

8. The circuit is with an ideal operational amplifier with  $\pm 10\ \text{V}$  supply. The output voltage is:



- (a)  $-200\ \text{mV}$  (b)  $-400\ \text{mV}$  (c)  $-600\ \text{mV}$  (d)  $-300\ \text{mV}$

9. A step voltage of 10 V applied to the circuit at  $t = 0$ . The current through the resistor  $R$  just after  $t = 0$  and at steady state are:

- (a) 100 mA, 50 mA
- (b) 50 mA, 50 mA
- (c) 100 mA, 100 mA
- (d) 75 mA, 75 mA

10. Which of the following addressing mode is not usable in XCH instruction of 8051 microcontroller?

- (a) Direct Addressing
- (b) Indirect Addressing
- (c) Register Addressing
- (d) Immediate Addressing

11. In a binary source, 0s occur three times as often as 1s. What is the information contained in the 1s?

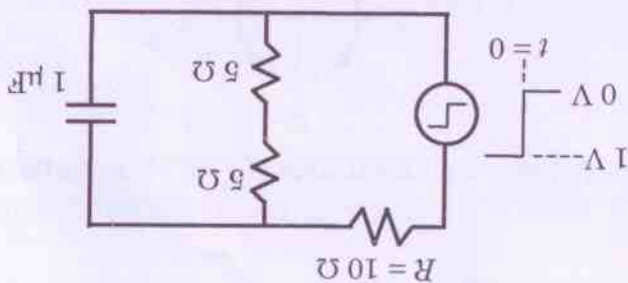
- (a) 0.415 bit
- (b) 0.333 bit
- (c) 3 bit
- (d) 2 bit

12. Spectrum of a signal  $x(t)$ , sampled at period  $T$ , is given by:

- (a)  $X_s(f) = \sum_{n=-\infty}^{\infty} X(f - \frac{j}{n})$
- (b)  $X_s(f) = \sum_{n=-\infty}^{\infty} X(nf - T)$
- (c)  $X_s(f) = X(f - \frac{j}{n})$
- (d)  $X_s(f) = \sum_{n=-\infty}^{\infty} X(f - nT)$

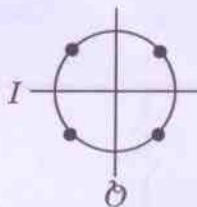
13. A bandpass signal occupies the bandwidth 390 KHz to 410 KHz. What minimum sampling frequency would you use from the options given below, so as to avoid aliasing?

- (a) 40 KHz
- (b) 820 KHz
- (c) 41 KHz
- (d) 800 KHz



14. A 12-bit ADC has input signal range of  $\pm 1$  V. The signal to quantization noise ratio if a sine wave signal with 0.25 V peak voltage is given as input is:
- (a) 62 dB (b) 72 dB (c) 74 dB (d) 48 dB

15. Identify the modulation schemes for the shown signal constellation diagram



- (a) ASK (b) MSK (c) FSK (d) QAM

16. Which of the following modulation scheme requires minimum power for transmission?
- (a) QPSK (b) 8-PSK (c) 16-QAM (d) 64-QAM

17. Which of the following channel coding scheme helps in correcting burst errors?
- (a) CRC (b) Convolution coding (c) Viterbi (d) Reed-Solomon

18. A 70 MHz carrier is QPSK modulated by a 1.544 Mbps T1 data stream. The transmitter employs a raised-cosine filter with  $\alpha = 0.2$ . What is the transmitted bandwidth of the signal?

- (a) 3705.6 KHz (b) 1852.8 KHz (c) 308.8 KHz (d) 926.4 KHz

19. If two tones  $f_1$  and  $f_2$  are amplified by a non-linear amplifier, which frequency components would be present in output?

- (a)  $f_1, f_2$

- (b)  $f_1, f_2, f_1 + f_2, f_1 - f_2$

- (c)  $f_1 + f_2, f_1 - f_2$

- (d)  $mf_1 \pm mf_2$ , where  $n$  and  $m$  are integers



20. A phase lock loop with a first order loop filter can track:
- (a) phase offset
  - (b) frequency offset
  - (c) frequency offset rate
  - (d) amplitude variation
21. The noise figure of a device is 2. If input SNR is 37 dB, what would be output SNR?
- (a) 18.5 dB
  - (b) 34 dB
  - (c) 40 dB
  - (d) 74 dB
22. What is the limit of  $E_b/N_0$ , below which reliable communication is not possible?
- (a) -10 dB
  - (b) -1.6 dB
  - (c) 0 dB
  - (d) 1.6 dB
23. A satellite communication link has uplink  $C/N_0$  of 50 dB-Hz and downlink  $C/N_0$  of 47 dB-Hz. What would be overall link  $C/N_0$ ?
- (a) 44 dB-Hz
  - (b) 45 dB-Hz
  - (c) 48.5 dB-Hz
  - (d) 53 dB-Hz
24. A signal transmitted from an Earth station bounces back from a geostationary satellite, with an altitude of 35864 km from the Earth surface. The range from the Earth station is 38200 km. The round trip time is about: (excluding processing delays and assuming  $c = 3 \times 10^8$  m/s)
- (a) 255 ms
  - (b) 127 ms
  - (c) 239 ms
  - (d) 120 ms
25. 1 mW in dBm is:
- (a) 0 dBm
  - (b) -30 dBm
  - (c) 30 dBm
  - (d) 1 dBm
26. Which of the following is not true?
- (a) MPEG-4 is a source coding technique
  - (b) Channel coding gives coding gain at the expense of bandwidth
  - (c) Source coding/decoding is done to remove errors
  - (d) Concatenated coding gives usually good performance

31. Consider a sequence  $x(n) = [2, 4, 6, 8, 0, 1, 3, 5, 7, 9]$ . Down-sample the sequence by 3 and then up-sample by 2. The resulting sequence is:  
 (a)  $[2, 0, 0, 0, 7, 0]$   
 (b)  $[2, 0, 0, 0, 0, 0, 7, 0, 0]$   
 (c)  $[2, 0, 8, 0, 3, 0, 9, 0]$   
 (d)  $[2, 2, 8, 8, 3, 3, 9, 9]$

30. Consider the discrete time signal  $x(n) = \{1, 1, 1, 1, 0.5, 0.5\}$ .  $y(n) = \text{conv}(\delta(n-1), x(n))$  is:  
 (a) 1  
 (b)  $\delta(n-1)$   
 (c)  $x(n-1)$   
 (d) 5

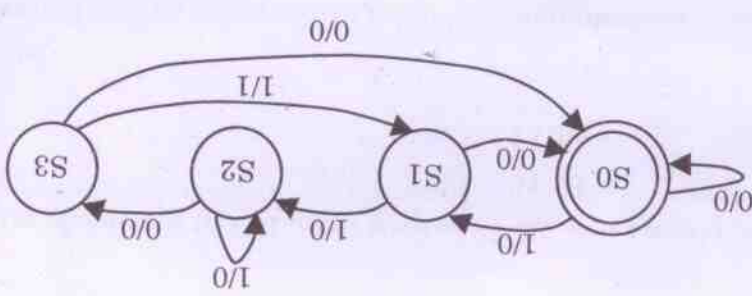
29. The rectangular window has relative side-lobe level:  
 (a) -13 dB  
 (b) -27 dB  
 (c) -32 dB  
 (d) -43 dB

The system is:  
 (a) A stable FIR filter  
 (b) A stable IIR filter  
 (c) An unstable FIR filter  
 (d) An unstable IIR filter

$$y(n) = 2x(n) + x(n-1) + 2y(n-1)$$

A digital signal processing system is described by the expression:

28. (a) 0010011010010101  
 (b) 0101011000010101  
 (c) 0011011010010101  
 (d) 1100100101001010



27. The following Finite State Machine (FSM) is used to detect a particular pattern in input data stream. Whenever the pattern is matched at input, output is set to '1' or else output is cleared to '0'. For which of the following data stream, output goes to '1' twice?

32. Power consumed in a CMOS circuit operating at frequency  $f$  is proportional to:
- (a)  $V_{cc} f$  (b)  $V_{cc}^2 f$  (c)  $V_{cc}^2 f^2$  (d)  $V_{cc}^2 f^2$
33. The phase velocity of a plane wave given by  $E_x = E_0 \cos(\omega t - \beta z)$  with a frequency of 5.0 GHz and a wavelength in the material medium of 3.0 cm is:
- (a)  $3.0 \times 10^8$  m/sec (b)  $1.5 \times 10^8$  m/sec (c)  $5 \times 10^8$  m/sec (d) None
34. If the reflected wave at the load of a transmission line is 20dB below the incident wave, the SWR at the load is:
- (a) 1.5 (b) 1.22 (c) 3.0 (d) 4.0
35. The highest frequency for which a circular coaxial transmission line having outer diameter = 3.1 mm and inner diameter = 1.3 mm can be operated in pure TEM mode (assuming free space medium between the two conductors) should be less than:
- (a) 12.2 GHz (b) 18.6 GHz (c) 26.5 GHz (d) 43.4 GHz
36. In a communication system at 300 MHz, the receiving antenna gain is 8 dBi, the transmitting antenna gain is 10 dBi and the transmitting power level is 25 watts, the distance between the transmitter and the receiver is 1 km, the power received at the receiving antenna port (assuming the propagation medium is loss-less):
- (a) 1 mW (b) 9.97  $\mu$ W (c) 99.7 nW (d) 0.0997 nW
37. A rectangular waveguide with air medium has dimensions  $a = 22.86$  mm and  $b = 10.6$  mm is fed by 3 GHz carrier from a coaxial cable, which of the following is false statement for TE<sub>01</sub> mode?
- (a) Propagating mode (b) Non-propagating mode (c) Propagating mode in case filled fully with dielectric material of proper dielectric constant (d) None of the above



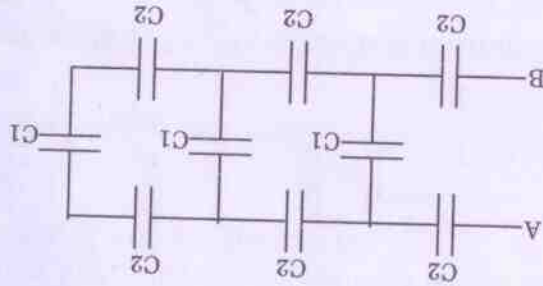
38.  $TM_{01}$  mode in rectangular perfect metallic waveguide is:  
 (a) Propagating mode  
 (b) Evanescent mode  
 (c) Non-existent mode  
 (d) None of the above
39. The directivity of a prime-focal parabolic reflector antenna is 30 dBi. If the efficiency of the antenna is 50%, the gain of the antenna is:  
 (a) 27 dBi  
 (b) 33 dBi  
 (c) 25 dBi  
 (d) 80 dBi
40. Ratio of skin depths of an Electromagnetic wave inside the conductor for the corresponding frequencies at 4 GHz and 9 GHz, considering the same material properties for both the frequencies is:  
 (a) 9:4  
 (b) 4:9  
 (c) 3:2  
 (d) 2:3
41. A Cassegrain reflector antenna has a sub-reflector whose geometrical shape is:  
 (a) Paraboloid  
 (b) Hyperboloid  
 (c) Ellipsoid  
 (d) Spherical
42. The beam-width and the directivity of an antenna are:  
 (a) Directly proportional  
 (b) Inversely proportional  
 (c) Independent of each other  
 (d) Equal
43. A lossless transmission line with characteristic impedance  $Z_0 = 50 \text{ ohm}$  is 30 m long and operates at 2 MHz. The line is shorted at the load, if the phase velocity = 0.6 times the velocity of light, the input impedance of the line is:  
 (a)  $75 \angle 90^\circ \text{ ohm}$   
 (b)  $\frac{50}{\sqrt{3}} \angle 180^\circ \text{ ohm}$   
 (c)  $\frac{100}{\sqrt{2}} \angle 180^\circ \text{ ohm}$   
 (d)  $\frac{75}{\sqrt{2}} \angle 270^\circ \text{ ohm}$



44. Two microwave sub-systems having respective return loss of 10 dB and 20 dB are cascaded together, the return loss at the input of the integrated system is:
- (a) 9.63 dB (b) 15.36 dB (c) 21.12 dB (d) 25.23 dB
45. A parabolic reflector antenna used for reception of data is 1 meter in diameter and operates at 30 GHz. The far field distance of this antenna for a quadratic phase error of 22.5 degree is:
- (a) 200 meter (b) 50 meter (c) 100 meter (d) 150 meter
46. A potential field is given by  $\Phi = 2xy^2 - 3y^2z$ . If  $\hat{x}$ ,  $\hat{y}$ ,  $\hat{z}$  are the unit vectors along  $x$ ,  $y$  and  $z$  directions respectively, the field intensity at (0, 1, 0) is:
- (a) 0 V/m (b)  $2\hat{x} - 3\hat{z}$  (c)  $-2\hat{x} + 3\hat{z}$  (d)  $2\hat{x} + 3\hat{z}$
47. The VSWR of a microwave unit is 1.5, the return loss is:
- (a) 14 dB (b) 16 dB (c) 18 dB (d) 11 dB
48. In two wire transmission line, two consecutive voltage minima are found at 20.6 cm and 25.6 cm. The operating frequency is:
- (a) 3.5 GHz (b) 3 GHz (c) 1 GHz (d) 2.5 GHz
49. A TEM mode transmission line is having distributed circuit parameters as  $R = 1 \text{ ohm/m}$ ,  $L = 200 \text{ nH/m}$ ,  $G = 300 \text{ }\mu\text{S/m}$ ,  $C = 60 \text{ pF}$ , the line is:
- (a) Loss-less (b) Lossy (c) Distortion-less (d) None of the above
50. A plane wave  $E = 100 \sin(\omega t - 10x) \text{ V/m}$  in a loss less medium with  $\mu = 4\mu_0$ ,  $\epsilon = \epsilon_0$  strikes another medium with 90 degree angle of incidence having  $\mu = 9\mu_0$ ,  $\epsilon = \epsilon_0$ , the reflection coefficient is:
- (a) 0.5 (b) 0.25 (c) 0.1 (d) 0.2

- (a) 4  $\mu\text{F}$
- (c) 1  $\mu\text{F}$

- (b) 3  $\mu\text{F}$
- (d) 2  $\mu\text{F}$



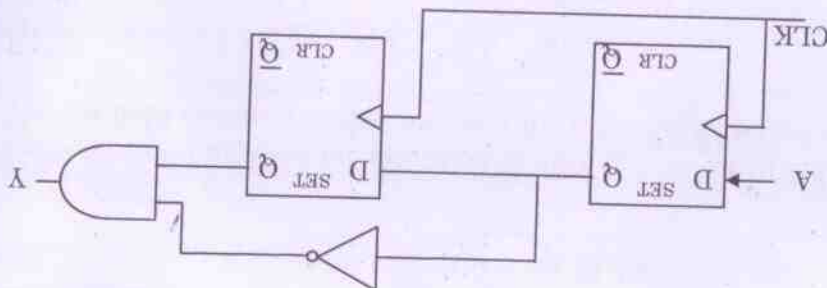
53. In the circuit if  $C1 = 2 \mu\text{F}$  and  $C2 = 3 \mu\text{F}$ , the equivalent capacitance between points A and B is:

- (a) 3.97 rad/m
- (c) 1.56 rad/m

- (b) 18.42 rad/m
- (d) 9.21 rad/m

52. A lossless transmission line has the distributed circuit parameters of inductance and capacitance per meter as 625 nH/m and 64 pF/m respectively, the phase constant of the line at 100 MHz is:

- (a) Falling edge detection of input A
- (b) Clock division by 2
- (c) Rising edge detection of input A
- (d) Clock division by 4



51. What is the functionality of following digital circuit? A is input data, CLK is system clock and Y is output.

54. If  $n$  number of MOSFETs with identical  $W/L$  are connected in series, then equivalent  $W/L$  is given by:

- (a)  $(W/L) \cdot n$
- (b)  $(W/L) / n$
- (c)  $(W/L) \cdot n^2$
- (d)  $(W/L) / (n^2)$

55. Which resource of FPGA implements combinational logic functionality?

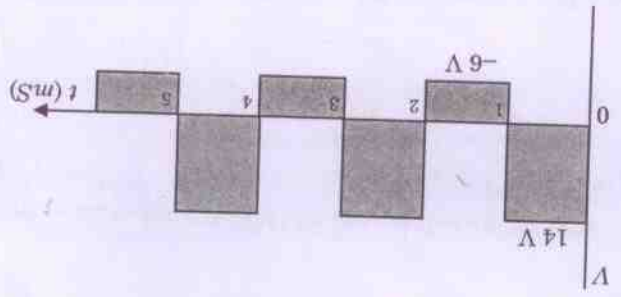
- (a) Block RAM
- (b) Configurable Logic Block (CLB)
- (c) Routing Switch Matrix
- (d) All of above

56. What will be the content of Accumulator, Register-B and Overflow Flag (OV) after execution of following 8051 micro-controller assembly code?

```
MOV A, #65h
MOV DPTR, #14h
DIV AB
DIV AB
```

- (a)  $A=00h, B=00h, OV=1$
- (b)  $A=05h, B=00h, OV=0$
- (c)  $A=00h, B=05h, OV=0$
- (d)  $A=05h, B=00h, OV=1$

57. Average value of the waveform is:

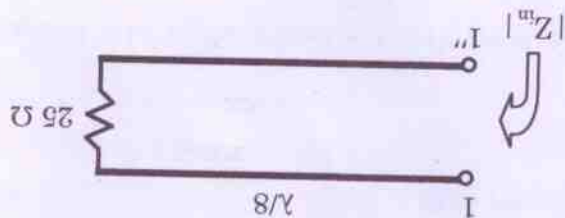


- (a) 8 V
- (b) 20 V
- (c) 10 V
- (d) 4 V



63. Magnitude of input impedance of a  $\lambda/8$  lossless  $50 \Omega$  transmission line terminated with  $25 \Omega$  is:

- (a)  $100 \Omega$
- (b)  $25 \Omega$
- (c)  $50 \Omega$
- (d) None of the above



64. Pipelining technique is used in microprocessor to improve which of the following parameter?

- (a) Power dissipation
- (b) Interrupt latency
- (c) Die size
- (d) Maximum clock frequency

65. In case of an ideal Class-F microwave power amplifier, time domain voltage and current waveform of the device have:

- (a) 50% overlap
- (b) Maximum overlap
- (c) No overlap
- (d) Less than 80% overlap

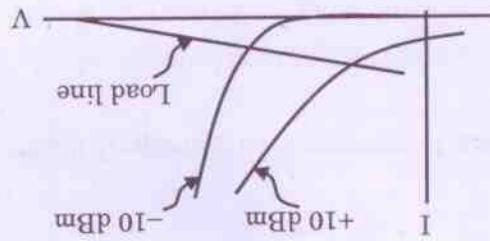
66. Reason for superior high frequency performance of metal-semiconductor diode compared to p-n junction diode is:

- (a) Higher conductivity of metal compared to semiconductor
- (b) No minority carrier storage effect in metal-semiconductor diode
- (c) Metal semiconductor junction does not rectify RF signal
- (d) Hole is the majority carrier in Schottky barrier diode operation

67. Which of the following diodes is most suitable for detection of microwave signal?

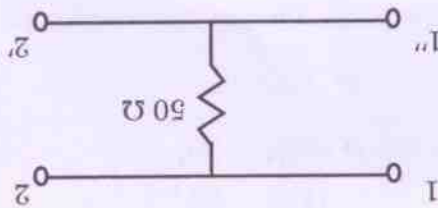
- (a) P-I-N diode
- (b) Schottky barrier diode
- (c) Varactor diode
- (d) P-N junction diode

- (a) Remains constant with the RF power level
- (b) Decreases with the increase of RF power level
- (c) Increases with the increase of RF power level
- (d) None of the above



70. The graph below shows operating load line and I-V characteristic of a Schottky diode at two different RF power levels. Under this bias condition RF resistance of the diode:

- (a)  $1/3 \angle 0^\circ$
- (b)  $1/2 \angle 180^\circ$
- (c)  $1/3 \angle 180^\circ$
- (d)  $1/2 \angle 0^\circ$



69. Input reflection coefficient 'S11' of the 2-port network for  $50 \Omega$  system is:

- (a) P-I-N diode
- (b) P-N junction diode
- (c) BJT
- (d) Step recovery diode

68. Which device is suitable for higher order RF frequency multiplier?

